

International IR Rectifier

ST180C..C SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)

350A

Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

case style TO-200AB (A-PUK)

Major Ratings and Characteristics

Parameters	ST180C..C	Units
$I_{T(AV)}$	350	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	660	A
@ T_{hs}	25	°C
I_{TSM}	5000	A
@ 60Hz	5230	A
I^2t	125	KA²s
@ 60Hz	114	KA²s
V_{DRM}/V_{RRM}	400 to 2000	V
t_q typical	100	μs
T_J	- 40 to 125	°C

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Bulletin I25164 rev. C 02/00

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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_{J\max}$ mA
ST180C..C	04	400	500	30
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

On-state Conduction

Parameter	ST180C..C	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	350 (140)	A	180° conduction, half sine wave double side (single side) cooled
	55 (85)	°C	
$I_{T(RMS)}$ Max. RMS on-state current	660	A	@ 25°C heatsink temperature double side cooled
I_{TSM} Max. peak, one-cycle non-repetitive surge current	5000		t = 10ms
	5230		t = 8.3ms
	4200		t = 10ms
	4400		t = 8.3ms
I^2t Maximum I^2t for fusing	125	KA ² s	100% V_{RRM} reapply
	114		No voltage reapply
	88		t = 10ms
	81		t = 8.3ms
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	1250	KA ² \sqrt{s}	t = 0.1 to 10ms, no voltage reapply
$V_{T(TO)1}$ Low level value of threshold voltage	1.08	V	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$, $T_J = T_{J\max}$)
$V_{T(TO)2}$ High level value of threshold voltage	1.14		($I > \pi \times I_{T(AV)}$, $T_J = T_{J\max}$)
r_{t1} Low level value of on-state slope resistance	1.18	mΩ	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$, $T_J = T_{J\max}$)
r_{t2} High level value of on-state slope resistance	1.14		($I > \pi \times I_{T(AV)}$, $T_J = T_{J\max}$)
V_{TM} Max. on-state voltage	1.96	V	$I_{pk} = 750A$, $T_J = T_{J\max}$, $t_p = 10ms$ sine pulse
I_H Maximum holding current	600	mA	$T_J = T_{J\max}$, anode supply 12V resistive load
I_L Max. (typical) latching current	1000 (300)		

Switching

Parameter	ST180C..C	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/ μ s	$T_J = T_{J\max}$, anode voltage $\leq 80\% V_{DRM}$
t_d Typical delay time	1.0	μ s	Gate current 1A, $di_g/dt = 1A/\mu$ s $V_d = 0.67\% V_{DRM}$, $T_J = 25^\circ\text{C}$
t_q Typical turn-off time	100		$I_{TM} = 300\text{A}$, $T_J = T_{J\max}$, di/dt = 20A/ μ s, $V_R = 50\text{V}$ $dv/dt = 20\text{V}/\mu\text{s}$, Gate 0V 100 Ω , $t_p = 500\mu\text{s}$

Blocking

Parameter	ST180C..C	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ μ s	$T_J = T_{J\max}$ linear to 80% rated V_{DRM}
I_{DRM} Max. peak reverse and off-state leakage current	30	mA	$T_J = T_{J\max}$, rated V_{DRM}/V_{RRM} applied

Triggering

Parameter	ST180C..C		Units	Conditions
P_{GM} Maximum peak gate power	10		W	$T_J = T_{J\max}$, $t_p \leq 5\text{ms}$
$P_{G(AV)}$ Maximum average gate power	2.0			$T_J = T_{J\max}$, $f = 50\text{Hz}$, $d\% = 50$
I_{GM} Max. peak positive gate current	3.0		A	$T_J = T_{J\max}$, $t_p \leq 5\text{ms}$
+ V_{GM} Maximum peak positive gate voltage	20		V	
- V_{GM} Maximum peak negative gate voltage	5.0			$T_J = T_{J\max}$, $t_p \leq 5\text{ms}$
I_{GT} DC gate current required to trigger	TYP.	MAX.	mA	Max. required gate trigger/ current/voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
	180	-		
	90	150		
V_{GT} DC gate voltage required to trigger	40	-	V	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$
	2.9	-		
	1.8	3.0		
I_{GD} DC gate current not to trigger	1.2	-	mA	Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied
	10			
	0.25			
V_{GD} DC gate voltage not to trigger			V	$T_J = T_{J\max}$

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Thermal and Mechanical Specification

Parameter	ST180C..C	Units	Conditions
T _J	Max. operating temperature range	°C	
T _{stg}	Max. storage temperature range		
R _{thJ-hs}	Max. thermal resistance, junction to heatsink	K/W	DC operation single side cooled
	0.17 0.08		DC operation double side cooled
R _{thC-hs}	Max. thermal resistance, case to heatsink	K/W	DC operation single side cooled
	0.033 0.017		DC operation double side cooled
F	Mounting force, ± 10%	N	
	4900 (500)	(Kg)	
wt	Approximate weight	g	
Case style	TO - 200AB (A-PUK)	See Outline Table	

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.015	0.015	0.011	0.011	K/W	T _J = T _j max.
120°	0.018	0.019	0.019	0.019		
90°	0.024	0.024	0.026	0.026		
60°	0.035	0.035	0.036	0.037		
30°	0.060	0.060	0.060	0.061		

Ordering Information Table

Device Code	ST	18	0	C	20	C	1	
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
1	- Thyristor							
2	- Essential part number							
3	- 0 = Converter grade							
4	- C = Ceramic Puk							
5	- Voltage code: Code x 100 = V _{RRM} (See Voltage Rating Table)							
6	- C = Puk Case TO-200AB (A-PUK)							
7	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)							
	1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)							
	2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)							
	3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)							
8	- Critical dv/dt: None = 500V/μsec (Standard value)							
	L = 1000V/μsec (Special selection)							

Outline Table

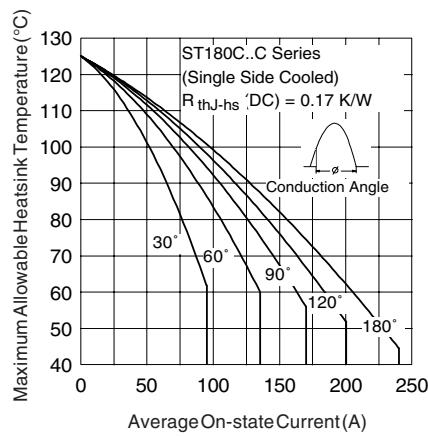
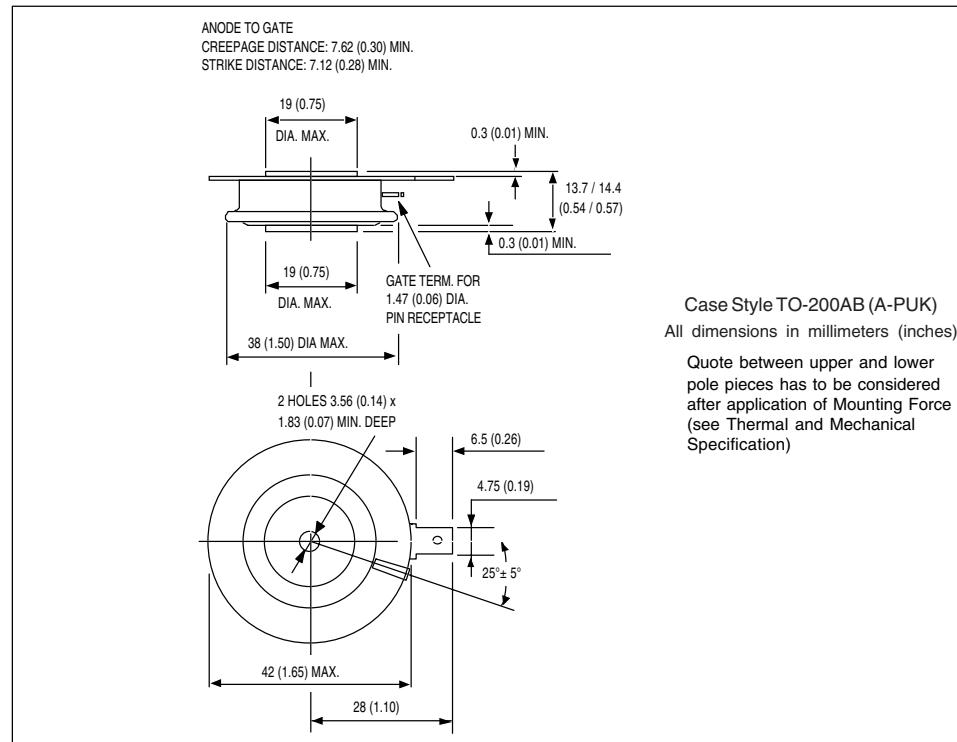


Fig. 1 - Current Ratings Characteristics

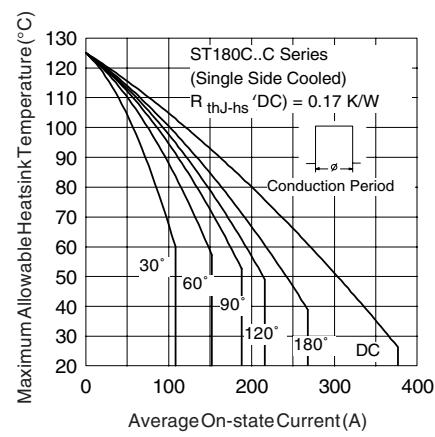
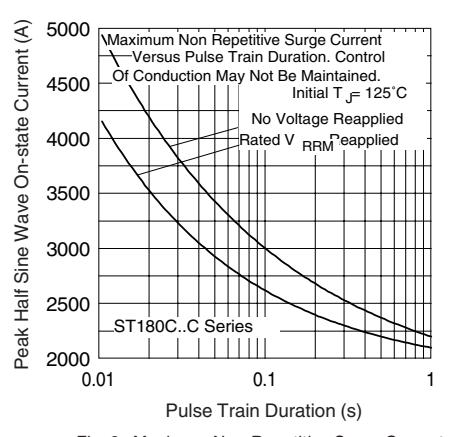
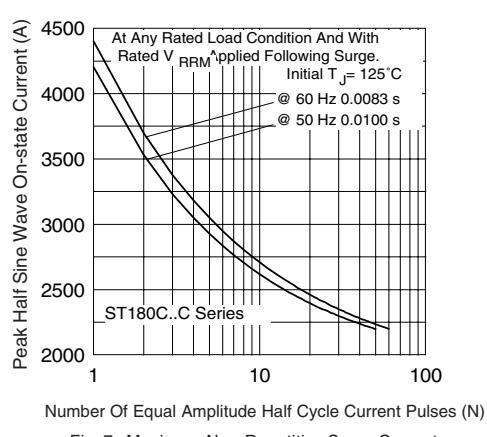
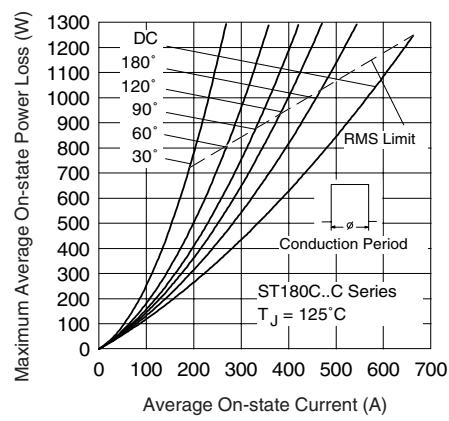
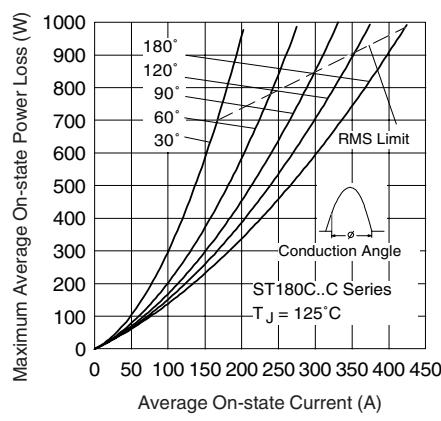
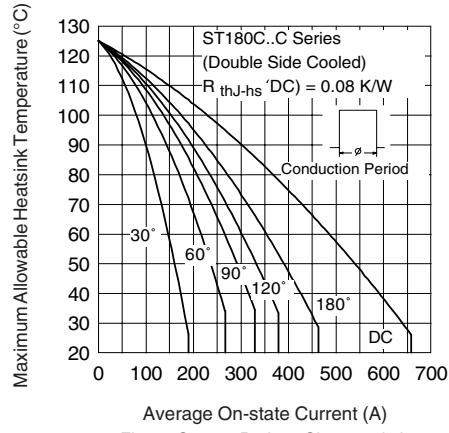
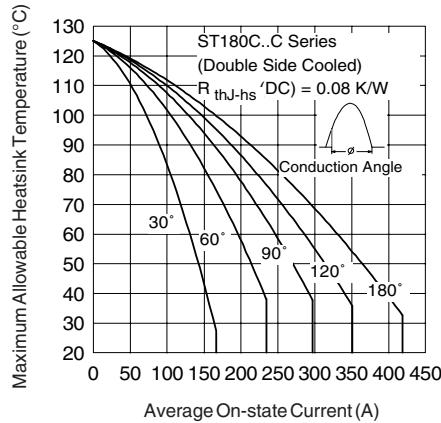


Fig. 2 - Current Ratings Characteristics

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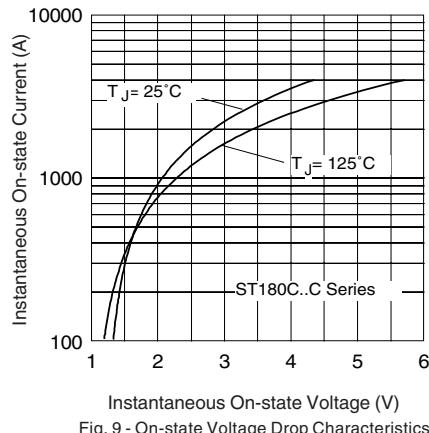


Fig. 9 - On-state Voltage Drop Characteristics

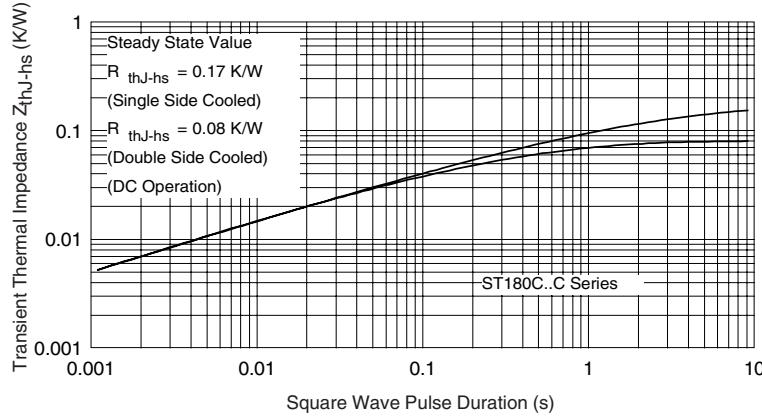


Fig. 10 - Thermal Impedance $Z_{\text{thJ-hs}}$ Characteristics

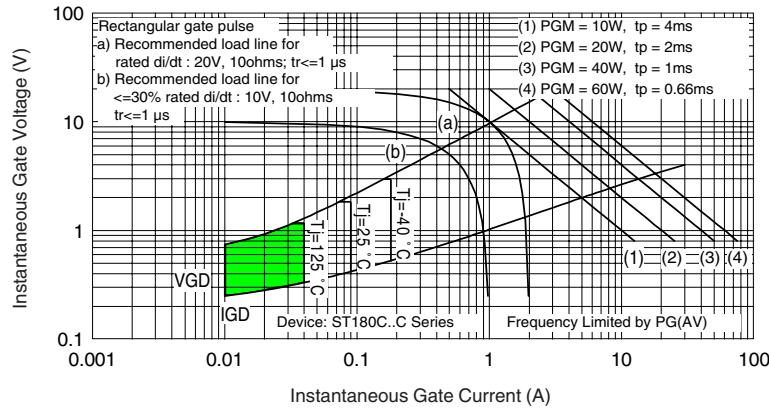


Fig. 11 - Gate Characteristics